

## LSJ201 N-CHANNEL JFET



## Linear Systems replaces discontinued Siliconix J201

# The LSJ201 is a high gain N-Channel JFET

This n-channel JFET is optimised for high gain. The part is particularly suitable for use in low power or high impedance amplifiers. The SOT-23 package is well suited for cost sensitive applications and mass production.

(See Packaging Information).

#### LSJ201 Benefits:

- High Input Impedance
- Low Cutoff Voltage
- Low Noise

### **LSJ201 Applications:**

- Battery powered amplifiers
- Audio Pre-Amplifiers
- Infra-Red Detector Amplifiers

FEATURES						
DIRECT REPLACEMENT FOR SILICONIX J201						
LOW CUT OFF VOLTAGE	V <sub>GS(off)</sub> ≤ 1.5					
HIGH GAIN	$A_{V} = 80 \text{ V/V}$					
ABSOLUTE MAXIMUM RATINGS @ 25°C (unless otherwise noted)						
Maximum Temperatures						
Storage Temperature	-65°C to +150°C					
Operating Junction Temperature	-55°C to +135°C					
Maximum Power Dissipation						
Continuous Power Dissipation	350mW					
MAXIMUM CURRENT						
Forward Gate Current (Note 1)	50mA					
MAXIMUM VOLTAGES						
Gate to Drain Voltage	V <sub>GDS</sub> = -40V					
Gate to Source Voltage	V <sub>GSS</sub> = -40V					

LSJ201 ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC	MIN	TYP.	MAX	UNITS	CONDITIONS
BV <sub>GSS</sub>	Gate to Source Breakdown Voltage	-40				$I_G = 1\mu A$ , $V_{DS} = 0V$
V <sub>GS(off)</sub>	Gate to Source Cutoff Voltage	-0.3		<b>-1.</b> 5	V	$V_{DS} = 15V, t_D = 10$ nA
I <sub>DSS</sub>	Drain to Source Saturation Current (Note 2)	0.2		1	mA	$V_{DS} = 15V, V_{GS} = 0V$
I <sub>GSS</sub>	Gate Reverse Current	-2		-1 <mark>0</mark> 0		$V_{GS} = -20V, V_{DS} = 0V$
l <sub>G</sub>	Gate Operating Current		-2		PΑ	$V_{DG} = 10V, I_D = 0.1 \text{mA}$
I <sub>D(off)</sub>	Drain Cutoff Current		2			$V_{DS} = 15V, V_{GS} = -5V$
<b>g</b> fs	Forward Transconductance	0.5			mS	$V_{DS} = 15V$ , $V_{GS} = 0V$ , $f = 1kHz$
C <sub>iss</sub>	Input Capacitance		4.5		pF	$V_{DS} = 15V, V_{GS} = 0V, f = 1MHz$
C <sub>rss</sub>	Reverse Transfer Capacitance		1.3			
$e_n$	Equivalent Noise Voltage		6		nV/√Hz	$V_{DS} = 10V, I_{D} = 1mA, f = 1kHz$

Note 1 - Absolute maximum ratings are limiting values above which LSJ201 serviceability may be impaired.

Note 2 – Pulse test: PW $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  3%

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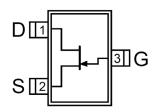
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Available Packages:

LSJ201 in SOT-23 LSJ201 in bare die.

Please contact Micross for full package and die dimensions

SOT-23 (Top View)



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